

## INCHANGE SEMICONDUCTOR

# Isc N-Channel MOSFET Transistor

## STP57N65M5

## • FEATURES

- With TO-262( I<sup>2</sup>PAK ) packaging
- High speed switching
- · Low gate input resistance
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

- Power supply
- Switching applications

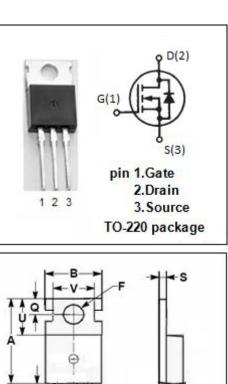
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

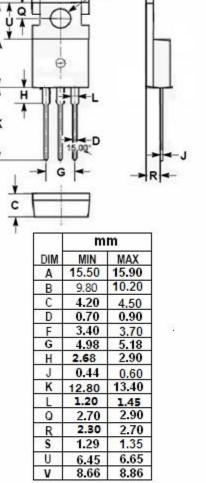
SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
V <sub>GSS</sub>	Gate-Source Voltage	±25	V
ID	Drain Current-Continuous@T_c=25 $^\circ\!\!\mathrm{C}$ T_c=100 $^\circ\!\!\mathrm{C}$	42 26.5	А
I <sub>DM</sub>	Drain Current-Single Pulsed	168	А
P <sub>D</sub>	Total Dissipation	250	w
Tj	Operating Junction Temperature	on Temperature 150	
T <sub>stg</sub>	Storage Temperature -55~15		°C

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.5	°C/W

1







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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\texttt{C}}\text{=}25^{\circ}\!\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	650			v
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> V; I <sub>D</sub> =0.25mA	3		5	v
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =21A		56	63	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0V			±0.1	μ Α
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0V;Tj=25℃ Tj=125℃			1 100	μ Α
VSDF	Diode forward voltage	I <sub>SD</sub> =42A, V <sub>GS</sub> = 0 V			1.5	V

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2